

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in an MLPAK33 (SOT8002) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Logic-level compatible
- Trench MOSFET technology
- MLPAK33 package (3.3 x 3.3 mm footprint)

3. Applications

- DC-to-DC converters
- Battery management
- Low-side load-switch
- Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Мах	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	30	V
V _{GS}	gate-source voltage	-		-20	-	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	-	22	А
Static chara	acteristics						
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 14.2 A; T _j = 25 °C		-	4.6	5.4	mΩ
		V _{GS} = 4.5 V; I _D = 12.3 A; T _j = 25 °C		-	5.8	7.2	mΩ
Dynamic ch	naracteristics						
Q _{G(tot)}	total gate charge	V_{DS} = 15 V; I _D = 12.3 A; V _{GS} = 4.5 V; T _j = 25 °C		-	11.6	17.4	nC

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².

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5. Pinning information

Table 2	able 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	S	source	1 2 3 4					
2	S	source	رفـفـفـف					
3	S	source		D				
4	G	gate						
5	D	drain		G-UFA				
6	D	drain	لمممك	mbb076 S				
7	D	drain						
8	D	drain	MLPAK33 (SOT8002-1)					

6. Ordering information

Table 3. Ordering information Type number Package				
	Name	Description	Version	
PXN5R4-30QL		plastic thermal enhanced surface mounted package; mini leads; 8 terminals; pitch 0.65 mm; 3.3 x 3.3 x 0.8 mm body	SOT8002-1	

7. Marking

Table 4. Marking codes	
Type number	Marking code
PXN5R4-30QL	8AP

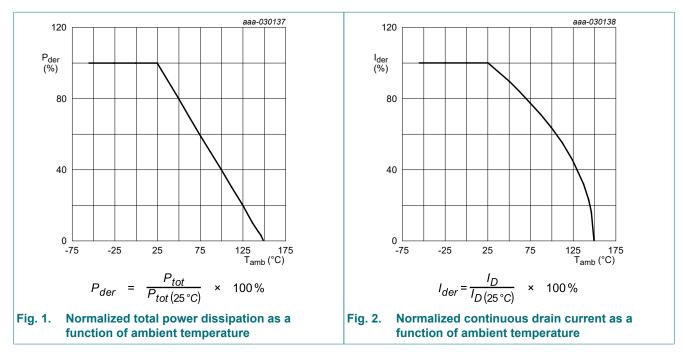
8. Limiting values

Table 5. Limiting values

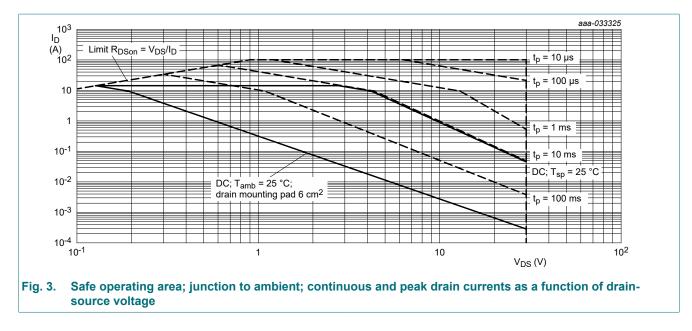
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	T _j = 25 °C		-	30	V
V _{GS}	gate-source voltage			-20	20	V
I _D	drain current	V _{GS} = 10 V; T _{amb} = 25 °C; t ≤ 5 s	[1]	-	22	А
		V _{GS} = 10 V; T _{amb} = 25 °C	[1]	-	14	А
		V _{GS} = 10 V; T _{amb} = 100 °C	[1]	-	9	А
		V _{GS} = 10 V; T _{sp} = 25 °C		-	66	А
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	101	А
P _{tot}	total power dissipation	T _{amb} = 25 °C; t ≤ 5 s	[1]	-	4.5	W
		T _{amb} = 25 °C	[1]	-	1.8	W
		T _{sp} = 25 °C		-	39	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drai	n diode					
I _S	source current	T _{amb} = 25 °C	[1]	-	1.8	А

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and mounting pad for drain 6 cm².



30 V, N-channel Trench MOSFET



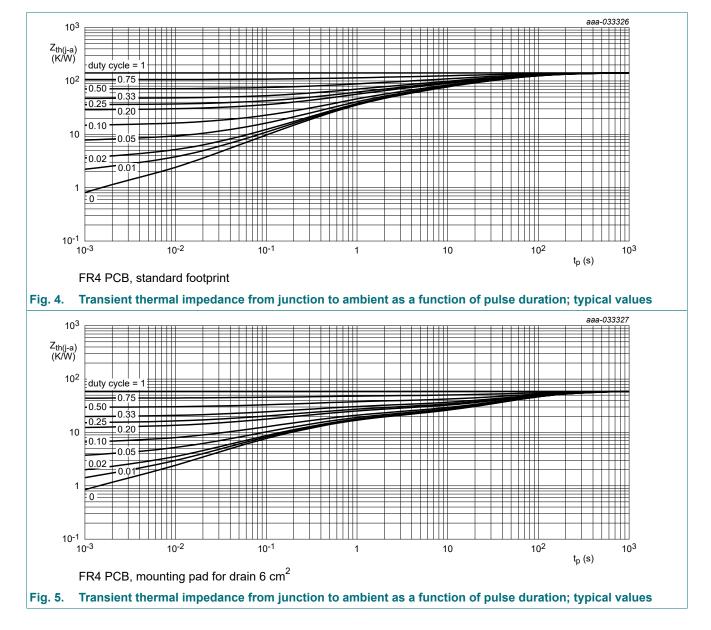
PXN5R4-30QL

9. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient		[1]	-	145	185	K/W
			[2]	-	55	70	K/W
		in free air; t ≤ 5 s	[2]	-	23	28	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point			-	2.3	3.2	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

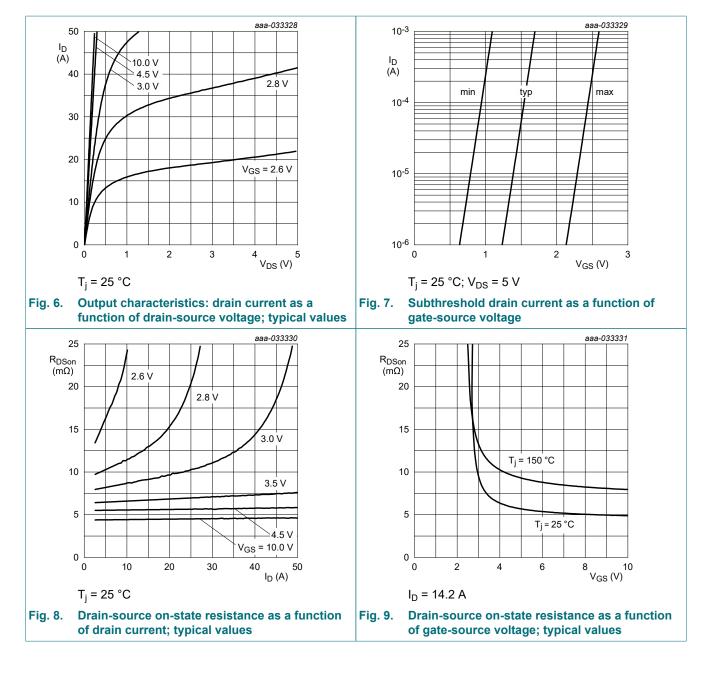
[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and mounting pad for drain 6 cm².



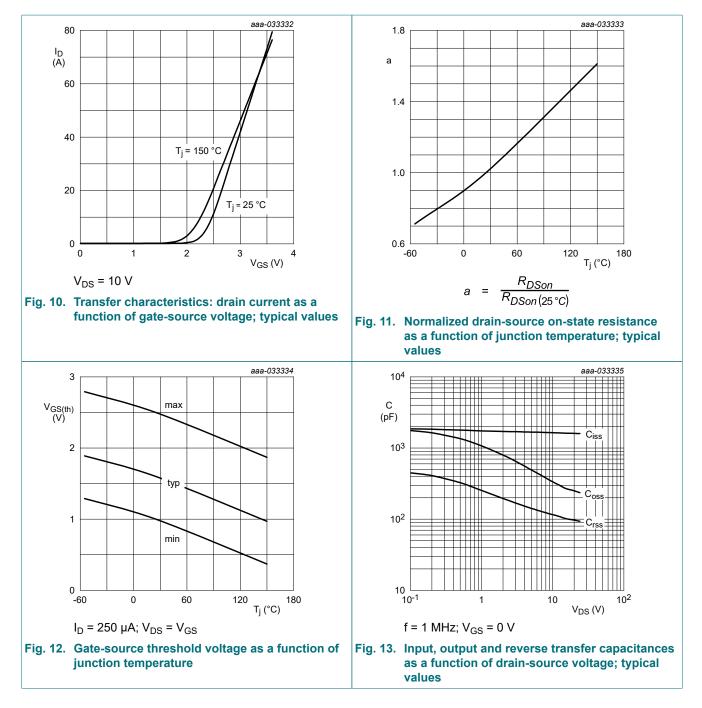
10. Characteristics

resistance $V_{GS} = 10 \text{ V}; \text{ I}_D = 14.2 \text{ A}; \text{ T}_j = 150 \text{ °C}$ - 7.5 8.9 m Ω	Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
breakdown voltage lp = 250 μ A; $V_{DS} = V_{GS}$; $T_j = 25 °C$ 1 1.6 2.5 V VGSm gate-source threshold $l_p = 250 \mu$ A; $V_{DS} = 0$, $T_j = 25 °C$ - - 1 μ A logs drain leakage current $V_{DS} = 30 V; V_{DS} = 0$, $T_j = 25 °C$ - - 100 nA Roson drain-source on-state resistance $V_{GS} = 10 V; I_p = 14.2 A; T_j = 25 °C$ - 4.6 5.4 mO $V_{GS} = 10 V; I_p = 14.2 A; T_j = 25 °C$ - 4.6 5.4 mO $V_{GS} = 10 V; I_p = 14.2 A; T_j = 25 °C$ - 5.8 7.2 mO $V_{GS} = 10 V; I_p = 14.2 A; T_j = 25 °C$ - 5.8 7.2 mO $V_{GS} = 10 V; I_p = 14.2 A; T_j = 25 °C$ - 5.8 7.2 mO $V_{DS} = 15 V; I_p = 12.3 A; T_j = 25 °C$ - 0.6 - 0 $Q_{G(tot)}$ post-threshold gate-source charge $V_{DS} = 15 V; I_p = 12.3 A; V_{GS} = 10 V;$ - 14.6 7.4 0 $Q_{G(tot)}$ post-threshold gate-source charge $V_{DS} = 15 V; I_p = 12.3 A; V_{GS} = 0 V;$ </td <td>Static chara</td> <td>cteristics</td> <td></td> <td></td> <td></td> <td></td> <td></td>	Static chara	cteristics					
voltage <	V _{(BR)DSS}		I_D = 250 µA; V_{GS} = 0 V; T_j = 25 °C	30	-	-	V
	V _{GSth}	•	I_D = 250 µA; V_{DS} = V_{GS} ; T_j = 25 °C	1	1.6	2.5	V
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	I _{DSS}	drain leakage current	V_{DS} = 30 V; V_{GS} = 0 V; T_j = 25 °C	-	-	1	μA
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	I _{GSS}	gate leakage current	V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25 °C	-	-	100	nA
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$			V _{GS} = -20 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-100	nA
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	R _{DSon}	drain-source on-state	V _{GS} = 10 V; I _D = 14.2 A; T _j = 25 °C	-	4.6	5.4	mΩ
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$		resistance	V _{GS} = 10 V; I _D = 14.2 A; T _j = 150 °C	-	7.5	8.9	mΩ
$\begin{array}{ c c c c c c c c c c c c c c c c c c c$			V _{GS} = 4.5 V; I _D = 12.3 A; T _j = 25 °C	-	5.8	7.2	mΩ
	9fs		V _{DS} = 10 V; I _D = 14.2 A; T _j = 25 °C	-	37	-	S
	R _G	gate resistance	f = 1 MHz	-	0.6	-	Ω
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Dynamic ch	aracteristics		<u> </u>			
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Q _{G(tot)}	total gate charge		-	24.2	36.3	nC
$\begin{array}{ c c c c c } \hline \mbox{QGS} & \mbox{gatessource charge} & \mbox{source charge} & \mbox{source charge} & \mbox{source charge} & \mbox{gatessource plateau} & \mbox{votage} & \mbo$				-	11.6	17.4	nC
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Q _{GS}	gate-source charge	T _j = 25 °C	-	4	-	nC
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	Q _{GS(th)}			-	2	-	nC
	Q _{GS(th-pl)}			-	2	-	nC
$ \begin{array}{ c c c c c c c } \hline voltage & & & & & & & & & & & & & & & & & & &$	Q _{GD}	gate-drain charge		-	3.3	-	nC
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	V _{GSpl}	-	V _{DS} = 15 V; I _D = 12.3 A; T _j = 25 °C	-	2.6	-	V
$ \begin{array}{ c c c c c } \hline C_{rss} & reverse transfer \\ capacitance \\ t_{d(on)} & turn-on delay time \\ t_r & rise time \\ t_{d(off)} & turn-off delay time \\ t_f & fall time \\ \hline Source-drain diode \\ \hline V_{SD} & source-drain voltage \\ t_r & reverse recovery time \\ Q_r & recovered charge \\ t_b & reverse recovery fall \\ \hline t_b & reverse recovery fall \\ \hline \end{array} \begin{array}{ c c c c } \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 270 & - & pr \\ \hline - & 13 & - & ns \\ \hline - & 11 & - $	C _{iss}	input capacitance		-	1600	-	pF
$\begin{tabular}{ c c c c c } \hline let let let let let let let let let let$	C _{oss}	output capacitance	T _j = 25 °C	-	270	-	pF
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	C _{rss}		-	-	98	-	pF
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	t _{d(on)}	turn-on delay time		-	9	-	ns
$\begin{array}{c c c c c c c c c c c c c c c c c c c $	t _r	rise time	R _{G(ext)} = 5 Ω; T _j = 25 °C	-	13	-	ns
Source-drain diode Is = 1.8 A; V_GS = 0 V; T_j = 25 °C - 0.7 1.2 V t_{rr} reverse recovery time Is = 1.8 A; dIs/dt = -100 A/µs; - 18 - ns Q_r recovered charge $V_{GS} = 4.5 V; V_{DS} = 15 V; T_j = 25 °C$ - 11 - nC t_a reverse recovery fall - 12 - ns t_b reverse recovery fall - 6 - ns	t _{d(off)}	turn-off delay time	_	-	11	-	ns
$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$	t _f	fall time		-	5	-	ns
t_{rr} reverse recovery time Q_r $I_S = 1.8 \text{ A}; dI_S/dt = -100 \text{ A}/\mus;$ $V_{GS} = 4.5 \text{ V}; V_{DS} = 15 \text{ V}; T_j = 25 ^{\circ}C$ -18-ns t_a reverse recovery rise timereverse recovery rise time-11-nC t_b reverse recovery fall-6-ns	Source-drai	n diode		· · · · ·		1	
Q_r recovered charge $V_{GS} = 4.5 \text{ V}; V_{DS} = 15 \text{ V}; T_j = 25 ^{\circ}C$ -11-nC t_a reverse recovery rise time-12-ns t_b reverse recovery fall-6-ns	V _{SD}	source-drain voltage	I _S = 1.8 A; V _{GS} = 0 V; T _j = 25 °C	-	0.7	1.2	V
$\frac{d_{r}}{d_{a}} = \frac{1}{100} + \frac{1}{100} $	t _{rr}	reverse recovery time		-	18	-	ns
time - 6 - ns	Q _r	recovered charge	V _{GS} = 4.5 V; V _{DS} = 15 V; T _j = 25 °C	-	11	-	nC
	t _a	-		-	12	-	ns
	t _b			-	6	-	ns

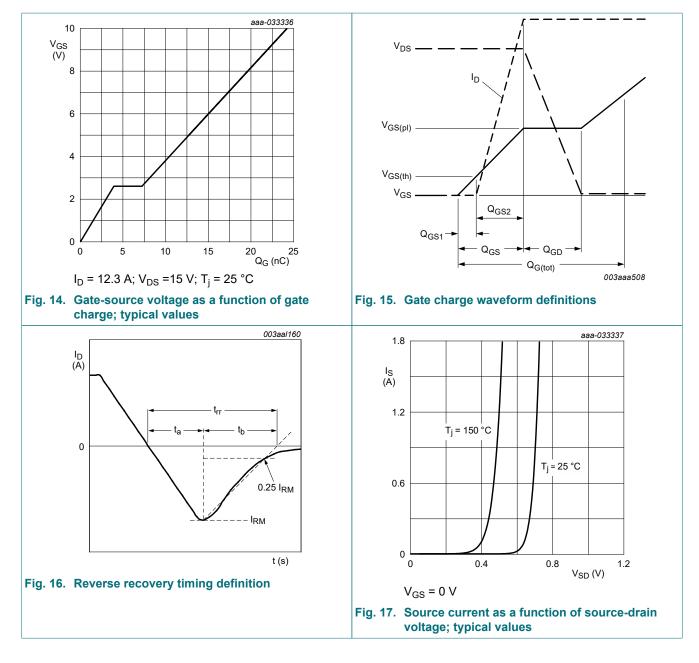
30 V, N-channel Trench MOSFET



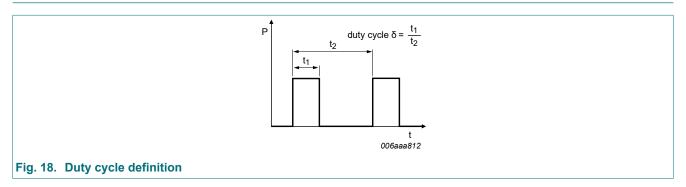
30 V, N-channel Trench MOSFET



30 V, N-channel Trench MOSFET

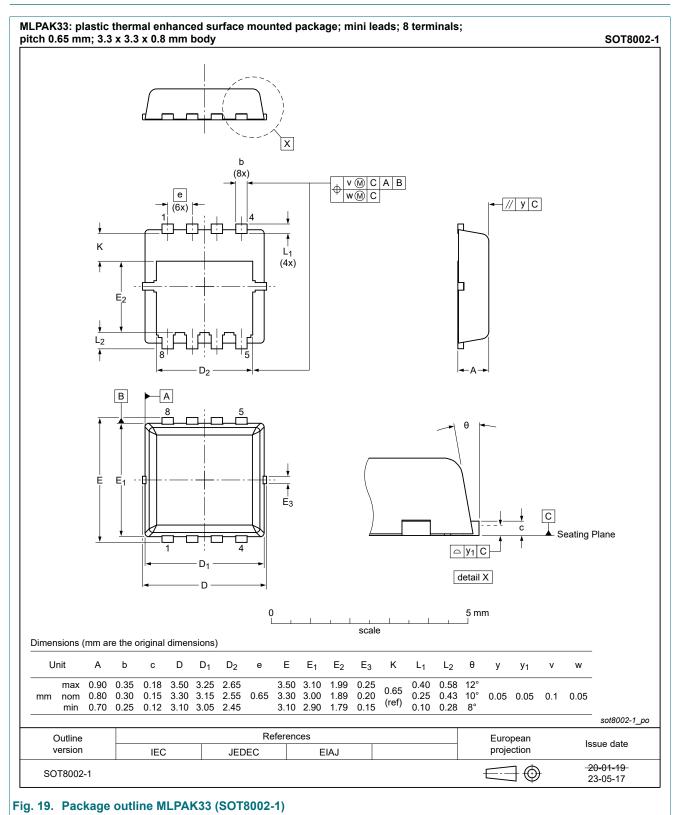


11. Test information

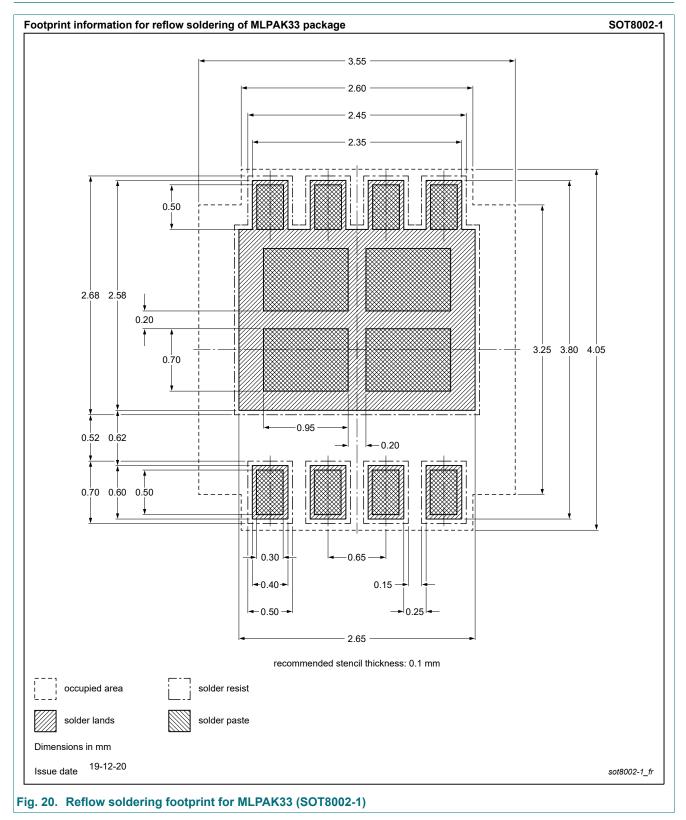


PXN5R4-30QL

12. Package outline



13. Soldering



14. Revision history

Table 8. Revision history								
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes				
PXN5R4-30QL/S500 v.2	20230731	Product data sheet	-	PXN5R4-30QL/S500 v.1				
Modifications:	Chapter "Package	Chapter "Package outline": drawing update						
PXN5R4-30QL/S500 v.1	20220610	Product data sheet	-	-				

PXN5R4-30QL

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

 Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <u>https://www.nexperia.com</u>.

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